## INTEGRATED CIRCUITS

## DATA SHEET

# 74LVT143.3V Hex inverter Schmitt trigger

Product specification

1996 Aug 28

IC24 Data Handbook





74LVT14

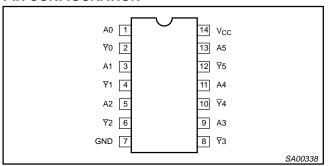
#### **DESCRIPTION**

The 74LVT14 is a high-performance BiCMOS product designed for  $V_{CC}$  operation at 3.3V. They are capable of transforming slowly changing input signals into sharply defined, jitter free output signals. In addition, they have greater noise margin than conventional inverters. Each circuit contains a Schmitt trigger followed by a Darlington level shifter and a phase splitter driving a TTL totem-pole output. The Schmitt trigger uses positive feedback to effectively speed-up slow input transitions, and provide different input threshold voltages for positive-going and negative-going input threshold (typically 600mV) is determined internally by resistor ratios and is insensitive to temperature and supply voltage variations.

#### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	PARAMETER CONDITIONS $T_{amb} = 25^{\circ}C;$ $GND = 0V$					
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation delay An to Yn	$C_L = 50pF;$ $V_{CC} = 3.3V$	3.2 3.0	ns			
C <sub>IN</sub>	Input capacitance	V <sub>I</sub> = 0V or 3.0V	3	pF			
I <sub>CCL</sub>	Total supply current	Outputs low; V <sub>CC</sub> = 3.6V	1.5	mA			

#### **PIN CONFIGURATION**



#### PIN DESCRIPTION

PIN NUMBER	SYMBOL	NAME AND FUNCTION
1, 3, 5, 9, 11, 13	An	Data inputs
2, 4, 6, 8, 10, 12	₹n	Data outputs
7	GND	Ground (0V)
14	V <sub>CC</sub>	Positive supply voltage

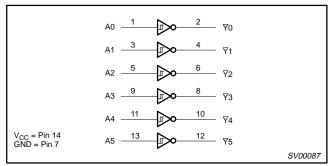
#### **FUNCTION TABLE**

INPUTS	OUTPUT
Dn	Qn
L	Н
Н	L

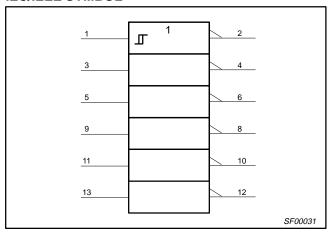
#### NOTES:

H = High voltage levelL = Low voltage level

#### **LOGIC DIAGRAM**



#### **IEC/IEEE SYMBOL**



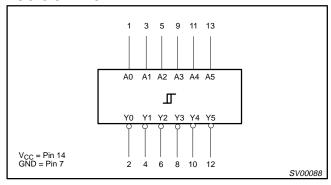
#### **ORDERING INFORMATION**

OINDERNING INTO OINII/ TITOTT				
PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
14-Pin Plastic SO	-40°C to +85°C	74LVT14 D	74LVT14 D	SOT108-1
14-Pin Plastic SSOP	-40°C to +85°C	74LVT14 DB	74LVT14 DB	SOT337-1
14-Pin Plastic TSSOP	−40°C to +85°C	74LVT14 PW	74LVT14 PWDH	SOT402-1

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#### LOGIC SYMBOL



#### ABSOLUTE MAXIMUM RATINGS1, 2

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V <sub>CC</sub>	DC supply voltage		-0.5 to +4.6	V
I <sub>IK</sub>	DC input diode current	V <sub>I</sub> < 0	-50	mA
V <sub>I</sub>	DC input voltage <sup>3</sup>		-0.5 to +7.0	V
I <sub>OK</sub>	DC output diode current	V <sub>O</sub> < 0	-50	mA
V <sub>OUT</sub>	DC output voltage <sup>3</sup>	Output in Off or High state	-0.5 to +7.0	V
	DC autout aurorat	Output in High state	-32	1
IOUT	DC output current	Output in Low state	64	mA
T <sub>stg</sub>	Storage temperature range		-65 to 150	°C

#### NOTES:

#### RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	LIM	UNIT	
STIVIBUL	FARAWEIER	MIN	MAX	UNIT
V <sub>CC</sub>	DC supply voltage	2.7	3.6	V
VI	Input voltage	0	5.5	V
$V_{IH}$	High-level input voltage	2.0		V
$V_{IL}$	Low-level Input voltage		0.8	V
I <sub>ОН</sub>	High-level output current		-20	mA
I <sub>OL</sub>	Low-level output current		32	mA
Δt/Δν	Input transition rise or fall rate; Outputs enabled		10	ns/V
T <sub>amb</sub>	Operating free-air temperature range	-40	+85	°C

<sup>1.</sup> Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

<sup>2.</sup> The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150°C.

<sup>3.</sup> The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

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#### DC ELECTRICAL CHARACTERISTICS

Over recommended operating conditions Voltages are referenced to GND (ground = 0V)

			L							
SYMBOL	PARAMETER	TEST CONDITIONS	Temp = -	∙40°C to	+85°C	UNIT				
			MIN	TYP <sup>1</sup>	MAX					
V <sub>T+</sub>	Positive-going threshold	V <sub>CC</sub> = 3.3V	1.5	1.7	2.0	V				
V <sub>T-</sub>	Negative-going threshold	V <sub>CC</sub> = 3.3V	0.9	1.1	1.3	V				
$\Delta V_{T}$	Hysteresis	V <sub>CC</sub> = 3.3V	0.4	0.6		V				
$V_{IK}$	Input clamp voltage	$V_{CC} = 2.7V; I_{IK} = -18mA$			-1.2	V				
		$V_{CC} = 2.7 \text{ to } 3.6 \text{V}; I_{OH} = -100 \mu \text{A}$	V <sub>CC</sub> -0.2							
$V_{OH}$	High-level output voltage	$V_{CC} = 2.7V; I_{OH} = -6mA$	2.4			٧				
		$V_{CC} = 3.0V; I_{OH} = -20mA$	2.0							
		$V_{CC} = 2.7V; I_{OL} = 100\mu A$			0.2	).2				
$V_{OL}$	Low-level output voltage	V <sub>CC</sub> = 2.7V; I <sub>OL</sub> = 24mA			0.5	V				
		$V_{CC} = 3.0V; I_{OL} = 32mA$			0.5	<u> </u>				
7	Input leakage current	$V_{CC} = 0 \text{ or } 3.6V; V_I = 5.5V$			10	μΑ				
'1	input leakage current	$V_{CC} = 3.6V$ ; $V_I = V_{CC}$ or GND			±1	μΑ				
I <sub>OFF</sub>	Output off current	$V_{CC} = 0V$ ; $V_I$ or $V_O = 0$ to 4.5V			±100	μΑ				
Іссн	Quiescent supply current	$V_{CC}$ = 3.6V; Outputs High, $V_{I}$ = GND or $V_{CC}$ , $I_{O}$ = 0			0.02	mA				
I <sub>CCL</sub>	Quiocochi ouppiy outfort	$V_{CC}$ = 3.6V; Outputs Low, $V_{I}$ = GND or $V_{CC}$ , $I_{O}$ = 0		1.5	3					
Δl <sub>CC</sub>	Additional supply current per input pin <sup>2</sup>	$V_{CC} = 3V$ to 3.6V; One input at $V_{CC}$ -0.6V, Other inputs at $V_{CC}$ or GND			0.2	μА				
C <sub>I</sub>	Input capacitance	V <sub>I</sub> = 3V or 0		3		pF				

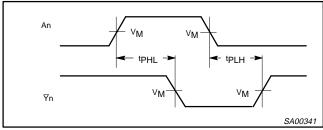
- All typical values are at V<sub>CC</sub> = 3.3V and T<sub>amb</sub> = 25°C.
   This is the increase in supply current for each input at the specificed voltage level other than V<sub>CC</sub> or GND

#### **AC ELECTRICAL CHARACTERISTICS**

SYMBOL		TEOT					
	PARAMETER	TEST CONDITION	V <sub>C</sub>	$_{C}$ = 3.3V $\pm$ 0.	3V	V <sub>CC</sub> = 2.7V	UNIT
			MIN	TYP	MAX	MAX	
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation delay An to Yn	Waveform 1	1.0 1.0	3.8 3.2	5.7 4.5	6.9 4.1	ns

#### **AC WAVEFORMS**

 $V_M = 1.5V$ ,  $V_{IN} = GND$  to 2.7V

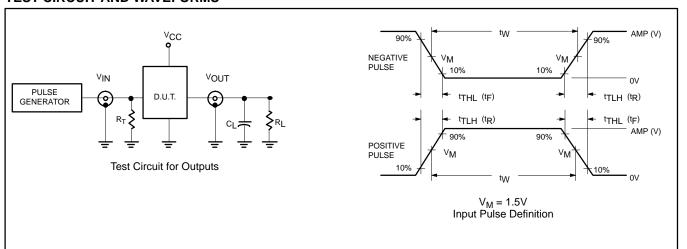


Waveform 1. Propagation delay for inverting outputs

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#### **TEST CIRCUIT AND WAVEFORMS**



#### **DEFINITIONS**

 $R_L$  = Load resistor; see AC CHARACTERISTICS for value.

 $C_L = Load$  capacitance includes jig and probe capacitance; see AC CHARACTERISTICS for value.

 $R_T$  = Termination resistance should be equal to  $Z_{OUT}$  of pulse generators.

FAMILY	IN	INPUT PULSE REQUIREMENTS											
	Amplitude	Rep. Rate	t <sub>W</sub>	t <sub>R</sub>	t <sub>F</sub>								
74LVT	2.7V	≤10MHz	500ns	≤2.5ns	≤2.5ns								

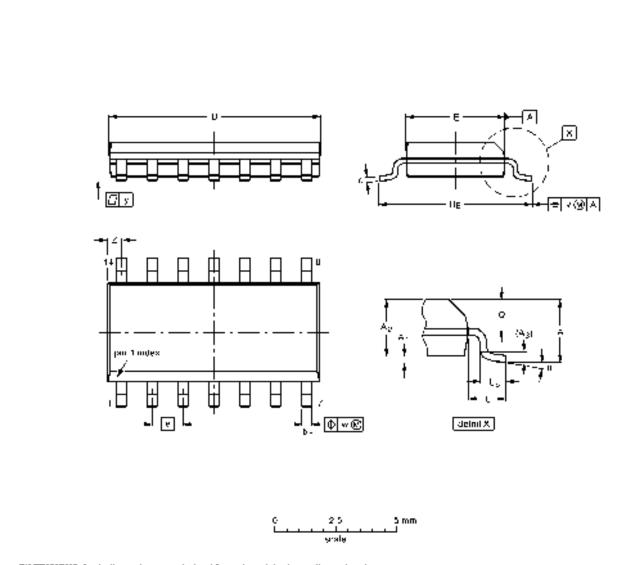
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#### SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1



#### DIMENSIONS (Inch dimensions are derived from the original mm dimensions)

UNIT	A max	4,	Az	43	PP	ė	<b>o</b> m)	€III	•	HE	١	Lp	Ģ	>	4	y	<b>Z</b> (1)	1.
mm	1.75	0.25 0.10	145 125	0.25	0.45 0.00	0.25 0.19	8.75 8.∞	4.0 3.0	1 27	52 58	į.	1.0 U,a	0.7 0.6	0 25	0.25	01	07 00	g°
inches		00048 00039		0.61		0.0049 0.0075		0 1t 0 15	0.050	023 023	0.041		0.028 0.024	0 01	0.01	0.004	0+Q9 0012	్

#### Note

1. Healistor metal profusions of 0.15 mm maximum per side are not included

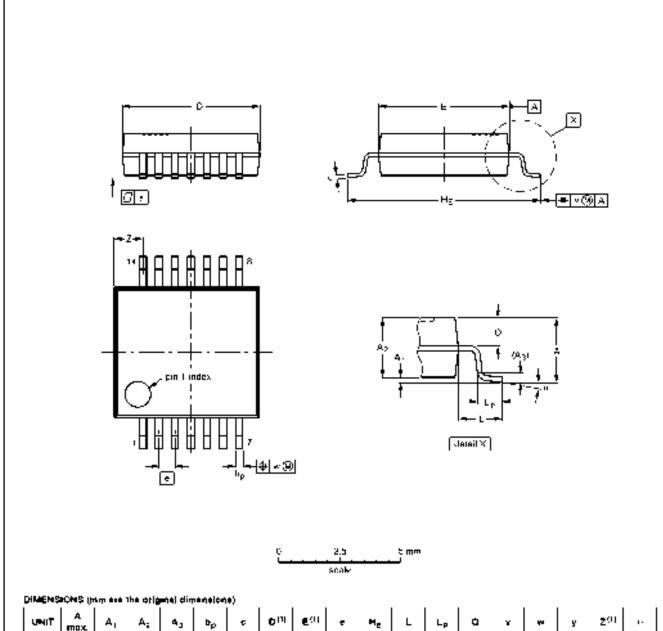
OUTLINE		REFER	EUROPEAN	IBBUE DATE			
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SOT108-1	076E06S	M5-012AB		<b>□ ◎</b>	<del>91 08 19</del> 95-01-29		

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#### SSOP14: plastic shrink small outline package; 14 leads; body width 5.3 mm

SOT337-1



UNIT	A mox.	Α,	A.	4,	Þр	ε	Olul	€01		HE	L	Lp	à	٧	-	y	201	1.	
mm	20	0.21 0.05	180 165	0.25	0.08 0.25	0.20 0.09	00 64	5.4 5.2	0.65	70 76	125	1.03 0.63	0.9 0.7	0.2	0.13	9.1	1 ¢ 0 9	O. A.	

#### Nove

1. Plastic or metal profusions of 0.25 mm maximum particle are not included

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	90 <b>1</b> 0074		MO-150AB			<del>95 82 94</del> 96-01-19

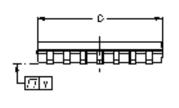
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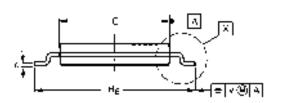
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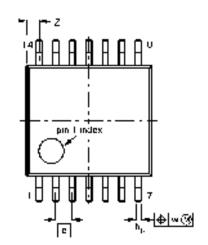
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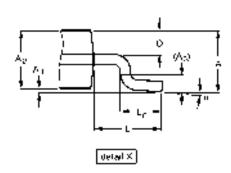
TSSOP14: plastic thin shrink small outline package; 14 leads; body width 4.4 mm

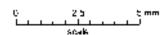
SOT402-1











#### DIMENSIONS (mm are the original cimenalons)

UNIT	A XEM	4,	Α,	۵,	b <sub>p</sub>	٠	ьm	<b>€</b> /21	•	<b>H</b> e	L	L <sub>P</sub>	a	v	₩.	¥	<b>Z</b> (0)	"	
mm	1.10	0.15 0.05	0.03 0.80	0.25	0.00 0.19	07	5.1 4.9	4.5 a,y	055	66 02	1.0	0.75 0.59	0.4 0.3	02	0 13	0.1	0.72 0.38	es Os	

#### Notes

- 1. Plastic or metal profitusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead provisions of 0.25 mm maximum per side are not included

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
YERSION	IEC	JEDEC	EITÌ		PROJECTION	ISSUE DATE	
SQT402-1		MO-150			€∃�	<del>- 94 07 42</del> 95-14-04	

## 3.3V Hex inverter Schmitt trigger

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**NOTES** 

### 3.3V Hex inverter Schmitt trigger

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DEFINITIONS							
Data Sheet Identification	Product Status	Definition					
Objective Specification	Formative or in Design	This data sheet contains the design target or goal specifications for product development. Specifications may change in any manner without notice.					
Preliminary Specification	Preproduction Product	This data sheet contains preliminary data, and supplementary data will be published at a later date. Phi Semiconductors reserves the right to make changes at any time without notice in order to improve des and supply the best possible product.					
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